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THE REACTIONS OF [TRIS(TRIMETHYLSILYL)METHYL]SILICON HALIDES AND HYDRIDES WITH ELECTROPHILIC REAGENTS *

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Summary

A study has been made of the reactions of compounds of the type $(Me_3Si)_3$ - $CSiR_2X$ (e.g. X = I, $R_2 = Me_2$, Ph_2 , PhMe, Et_2 , or EtMe; X = H, $R_2 = Me_2$, Et_2) with electrophilic reagents such as $AgNO_3$, AgOAc, AgO_2CCF_3 , $Hg(NO_3)_2$, Hg(OAc)₂, HgCl₂ and HgBr₂, in alcohols, AcOH, CF₃CO₂H, or mixtures of these. Reactions of (Me₃Si)₃CSiPh₂I take place exclusively with rearrangement, to give products of the type $(Me_3Si)_2C(SiMe_2Y)(SiPh_2Me)$ (e.g. with AgNO₃ – i-PrOH – MeOH, a mixture of products, with $Y = NO_3$, OMe or OPr-i is formed), while the compounds $TsiSiR_2I$ with $R_2 = Et_2$, PhMe, or EtMe give both rearranged products, (Me₃Si)₂CH(SiMe₂Y)(SiR₂Me), and unrearranged products, $(Me_3Si)_3CSiR_2Y$. With AgNO₃ or Hg(NO₃)₂ in MeOH, added NaNO₃ does not increase the SiONO₂/SiOMe product ratio. The reactions of (Me₃Si)₃-CSiMe₂H and (Me₃Si)₃CSiMe₂I with Hg(NO₃)₂ - AcOH - MeOH give virtually the same product distribution, as do those of (Me₃Si)₃CSiMe₂I and (Me₃Si)₃Si- Me_2Br with $AgNO_3 - MeOH$. (The bromide reacts much more slowly than the iodide in the latter case, and no reaction was observed in the case of $(Me_3Si)_3$ - $CSiMe_2Cl$). The iodide (Me₃Si)₃SCiMe₂I undergoes solvolysis slowly in CF₃CO₂H alone, and added NaO₂CCF₃ has no effect.

The results are interpreted in terms of the formation of a cationic intermediate by abstraction of X^- from $(Me_3Si)_3CSiR_2X$ by the electrophile. A structure involving a Me group bridging the 1- and 3-silicon atoms is favoured for this cation, with the nucleophile subsequently attacking at either of these atoms.

Introduction

We have previously noted that because of steric hindrance tris(trimethylsilyl)methyl-silicon compounds, $(Me_3Si)_3CSiRR'X$, (e.g. X = halogen) are

* No reprints available.

extremely inert towards direct displacement of X by nucleophiles [1,2]. Thus their study seemed to offer a good prospect of observing reactions proceeding through siliconium ions *. The investigation described below of reactions of $(Me_3Si)_3CSiR_2X$ species with electrophilic reagents in protic media has shown that cationic species are indeed involved, and are associated with novel rearrangements, but these species may not be simple siliconium ions. (For a brief preliminary account see ref. 5). Some of the reactions described involve the production of organosilicon chlorides, bromides, nitrates, or acetates in alcoholic media or acetic acid; the novelty of this will be apparent to organosilicon chemists.

In the subsequent discussion we shall, as previously [1,2,5], frequently use the symbol Tsi (denoting the "trisyl" group) for $(Me_3Si)_3C$.

Results and discussion

Our first observation of interest was that none of the halides $TsiSiPh_2X$ or $TsiSiMe_2X$ (X = Cl, Br or I) undergo solvolysis in refluxing methanol. Thus these halides, even the iodides which have relatively weak Si—Hal bonds, show no tendency to react by a simple S_N1 type mechanism under conditions commonly associated with such reactions in the case of alkyl halides. Ionization might be expected to be especially favoured for $TsiSiPh_2X$ compounds, since (a) the ion $TsiSiPh_2^+$ should be stabilized to some extent by conjugation with the Ph groups and by hyperconjugative electron release from the Tsi group (compare the stabilization of the ion $Me_3SiCH_2CH_2^+$ [6], and (b) the ionization would be accompanied by considerable release of steric strain. However, steric hindrance to solvation would have some counter influence.

We next studied in detail the reactions of some TsiSiR₂X compounds with silver or mercury(II) salts in alcohols or acetic acid, and the results are shown in Table 1, and discussed below.

The chloride $TsiSiMe_2Cl$ was found to undergo no reaction with silver nitrate in methanol during 20 h under reflux (Rct. 48), but the corresponding bromide underwent about 50% reaction under these conditions to give a mixture of the methoxide $TsiSiMe_2OMe$ and the nitrate $TsiSiMe_2ONO_2$ (Rct.49). However, the corresponding diphenyl derivative, $TsiSiPh_2Br$ underwent no significant reaction in 36 h (Rct. 14). The iodides $TsiSiPh_2I$ and $TsiSiMe_2I$ were very much more reactive in reactions with $AgNO_3 - MeOH$ and a variety of other electrophilic reagents in protic solvents.

More restricted studies were made on the iodides $TsiSiEt_2I$ and TsiSiEtMeI, and on the hydrides $TsiSiMe_2H$ and $TsiSiEt_2H$, which were also found to react readily with electrophiles, and the results for these are also shown in Table 1.

We first examined the reactions of the dimethyl derivatives $TsiSiMe_2X$ (X = I or H). The participation of siliconium ion intermediates seemed to be indicated by the following features of the results.

(a) Mixtures of products resulting from reactions with solvent molecules and counter anions were commonly obtained, e.g. of (i) TsiSiMe₂OMe and TsiSi-

^{*} By siliconium ions we mean ions such as H₃Si^{*} and its derivatives. For a review of attempts to detect siliconium ions in solution see ref. 3, and for later leading references see ref. 4.

 Me_2ONO_2 from $AgNO_3$ — MeOH (Rcts. 16 and 17); (ii) TsiSiMe₂OAc and TsiSi-Me₂ONO₂ from $Hg(NO_3)_2$ — AcOH (Rct. 31); (iii) TsiSiMe₂OAc and TsiSiMe₂Cl from $HgCl_2$ — AcOH (Rct. 45); and (iv) of TsiSiMe₂OMe, TsiSiMe₂OAc, and TsiSiMe₂ONO₂ from AgNO₃ in 1 : 1 MeOH — AcOH (Rct. 27).

(b) The proportion of nitrate product obtained with $AgNO_3$ or $Hg(NO_3)_2$ in MeOH or with $AgNO_3$ in i-PrOH was not significantly increased by the addition of an excess of nitrate ion (Rcts. 16–19; 21, 22; 28, 29) which argues strongly against simultaneous attack of the nucleophile at silicon and of the electrophile at iodine.

(c) The composition of the product mixture from $\text{TsiSiMe}_2\text{I}$ is the same as that from $\text{TsiSiMe}_2\text{H}$ in the reaction with $\text{Hg}(\text{OAc})_2 - \text{MeOH} - \text{AcOH}$ (Rcts. 38, 52). Similarly, the composition of the product mixture from $\text{TsiSiMe}_2\text{I}$ is the same as that from the much less reactive $\text{TsiSiMe}_2\text{Br}$ in the reaction with AgNO_3 in MeOH (Rcts. 16, 49). This argues in favour of a common intermediate rather than concerted nucleophilic and electrophilic attack.

Study of the reactions of TsiSiPh₂I (Rcts. 1–13) then revealed, however, that the reaction was more complex, since the products were shown unambiguously by their ¹H NMR spectra to be of the type $(Me_3Si)_2C(SiMe_2Y)$ -(SiPh₂Me) rather than the expected $(Me_3Si)_3CSiPh_2Y$; that is, the nucleophile Y attaches at a silicon atom [denoted Si(3)] different from that [denoted Si(1)] from which X leaves, and there is a corresponding $3 \rightarrow 1$ migration of a methyl group.

We suggest that the methyl-bridged cationic species (I) is formed by movement of a Me group as X is removed by the electrophile in the rate-determining step of the reaction. The nucleophile Y can then attack, to break the bridge, either at Si(1) or Si(3), to give respectively, the unrearranged product $(Me_3Si)_3$ - $CSiR_2Y$ or the rearranged product $(Me_3Si)_2C(SiMe_2Y)(SiR_2Me)$. In these highly sterically hindered systems, the dominant (though not necessarily the only) factor determining the position of attack is likely to be the degree of hindrance at each centre, and thus for $R_2 = Ph_2$ the substantially greater hindrance at Si(1) would markedly favour formation of the rearranged product, and this is apparently exclusively produced *.

As the difference of the degree of hindrance at Si(1) and Si(3) becomes smaller, we should expect an increasing proportion of unrearranged product; in keeping with this, in reactions with Hg(OAc)₂ — AcOH, while TsiSiPh₂I gives 100% of rearranged product (Rct. 13), TsiSiPhMeI gives a 78/22 ratio of rearranged to unrearranged product (Rct. 15), and TsiSiEt₂I gives an approximately 50/50 ratio (Rct. 55). We have no direct evidence, in the absence of experiments with labelled compounds, that any rearrangement occurs in the case of TsiSiMe₂X derivatives, but it seems safe to assume that it does.

We should note at this point that rearranged products could also be formed if, instead of the bridged ion I, an equilibrated mixture of the classical ions III and IV were formed, as in Equation 1, after removal of X^- . The nucleophile

^{*} In the reaction of TsiSiPh₂I with AgNO₃-i-PrOH, along with (Me₃Si)₂C(SiMe₂OPr-i)(SiPh₂Me) and (Me₃Si)₂C(SiMe₂ONO₂)SiPh₂Me, a second isoproxide is produced in small amount (Rct. 5). We previously described this as unrearranged TsiSiPh₂OPr-i [5] but reexamination of the ¹H NMR spectrum reveals that there is some doubt about his, and we are postponing consideration of this product until we have made it on a larger scale and identified it unambiguously.

keac-	Substrate	Solvent ^a	Salt(s) and amount	Time ^b	Products and proportion (%) ^c	Notes	22
rion	K2X		(IOUIII)		Y in (Me ₃ Si) ₂ C(SiMe ₂ Y) (SiR ₂ Me)	Y in (Me ₃ SI) ₃ CSIR ₂ Y	
	Phol. 0.10	MeOH	AgNO ₃ , 0.40	10 min	OMe, 87; ONO ₂ , 13		•
		AcOH	AgNO3. 0.14	10 min	0Ac, 90; 0NO ₂ , 10	-	
		McOH	AgNO ₃ , 0,20; NaNO ₃ , 1,0	10 min	OMe, 85; ONO ₂ , 15		
		I-PrOH	AgNO3, 0.14	10 min	OPr-i, 28; ONO ₂ , 62	? OPr-I, 10	q
10		I-PrOH - McOH	AgNO3, 0,14	15 min	OPr-i, 22; OMe, 61; ONO ₂ , 17		
		i-PrOH - MeOH (1/2)	AgNO ₃ , 0.14	16 min	OPr-i, 15; OMe, 73; ONO2, 12		
~		MeOH - AcOH	AgNO ₃ , 0,14	5 min	OAc, 61; OMe, 30; ONO2, 9	-	
~		i-PrOH - AcOH (1/2)	AgNO3, 0.14	10 min	OAc, 82; OPr-I, 9; ONO2, 9	• •	
		MeOH	AgOAc, 0.14	1.5 h	OAc, 94; OMe, 6		
10		AcOH	AgOAc, 0.14	7 min	OAc, 100		
11		MeOH - AcOH	AgOAc, 0.14	3 min	OAc, 55; OMe, 45	-	
12		AcOH	Hg(NO ₃) ₂ , 0.30	3 min	OAc, 90; ONO ₂ , 10		
3		AcOH	Hg(OAc) ₂ , 0.31	3 min	OAc, 100		9
14	$Ph_2Br, 0.15$	MeOH	AgNO ₃ , 0.60	36 h	Br (SM), 100		,
15	PhMcI, 0.10	AcOH	AgOAc, 0.14	0.5 h	OAc, 78	0Ac, 22	υ
16	Me ₂ 1, 0.10	MeOH	A6NO3, 0.12	0.5 h	OMe, 76; ONO ₂ , 24		
17	i	MeOH	AgNO3, 0.24	0.5 h	OMe, 75; ONO ₂ , 25		
18		MeOH	AgNO ₃ , 0.18; NaNO ₃ , 1.0	0.6 h	OM ⁶ , 76; ONO ₂ , 24		
19		MeOH	AgNO3, 0.18; LINO3, 1.0	0.5 h	OMe, 78; ONO ₂ , 22		
20		HOrd-1	AgNO3, 0.12	0.5 h	OPr-I, 33; ONO ₂ , 67		
21		HOrd-I	A6NO3, 0.24	0.5 h	OPr-1, 33, ONO ₂ , 67		•
22		HO14-I	AgNO ₃ , 0.18; NuNO ₃ , 1.0	0.5 h	OPr-i, 34; ONO ₂ , 66		
23		t-BuOH	AgNO3, 0.18	0.5 h	OBu-t, 34; ONO2, 66		
24		AcOH	AgNO 3, 0.18	0.5 h	OAc, 91; ONO ₂ , 9		
26		AcOH	AgNO ₃ , 0.18; NaNO ₃ , 1.0	0.5 h	OAc, 75; ONO ₂ , 25		5
26		i-PrOH - MeOH	AgNO ₃ , 0.18	0.5 h	OMe, 58; ONO ₂ , 42		
27		McOH - AcOH	AgNO ₃ , 0.18	0.5 h	OAc. 45; OMe, 29; ONO2, 26		
28		MeOH	Hg(NO ₃) ₂ , 0.30	0.5 h	OMe, 75; ONO ₂ , 25		
20		MeOH	Hg(NO ₃) ₂ , 0.30; NaNO ₃ , 1,0	0.5 h	OMe, 71; ONO ₂ , 29	-	
30		I-PrOH	Hg(NO ₃)2, 0.31	0.5 h	POr-1, 59; ONO2, 41		
31		AcOH	$Hg(NO_3)_2$, 0.30	0.5 h	OAc, 78; ONO ₂ , 22		
32		AcOH	Hg(NO ₃) ₂ , 0.30; NaNO ₃ , 1.0	0.5 h	OAc, 66; ONO ₂ , 34		
33		t-BuOH	Hg(NO ₃)2, 0.31	1 h	OBu-t, 38; ONO ₂ , 62		
34		I-PrOH - MeOH	Hg(NO ₃) ₂ , 0.31	0.5 h	OMe, 49; OPr-i 31; ONO2, 20		
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38 38 38		MeOH - AcOH		0.5 h	OM6, 32; OA6, 68		
39			HRUACh, U.J.				
		MeOH	HgSO4.0.33	0.5 h	OMe. 100		50
40		McOH	HgCl ₂ , 0.37	2 h	I(SM), 76; OMe, 24		
41		MeOH	HgBr ₂ , 0,28	2 h	I(SM), 100		
42		I-PrOH	HgSO4, 0.33	2 h	I(SM), 100		- a
43		4-BuOH	HgSO4, 0.33	2 h	I(SM), 100		
44		AcOH	HgSO4, 0.33	2 h	OAc, 100		່
46		AcOH	HgCl2, 0.37	2 h	I(SM), 43; OAc, 34; Cl, 22		5 5 7
46		AcOH	HgBr2, 0.28	2 h	I(SM), 61; OAc, 19; Br, 20		8 2 2
47		AcOH	Hg(OAc)2, 0.37; NaCl (excess)	2 h	I(SM), 33; OAe, 41; Cl, 26		=
48	Me2C1, 0.15	MeOH	AgNO3, 0.60	20 h	CI(SM), 100		
49	Mc2Br, 0.16	M ₆ OH	AgNO3, 0.60	20 h	Br(SM), 40; OMe, 45; ONO ₂ , 15		
60	Me2H, 0,15	MoOH - AcOH	AgNO ₃ , 0.18	1.5 h	H(SM), 100		
61	M ₀₂ H, 0.15	MeOH - AcOH	Hg(NO ₃) ₂ , 0.31	2 h	OMe, 19; OAc, 81	4	
62		McOH - AcOH	Hg(OAc)2, 0.31	2 h	OMe, 34; OAc, 66		
63		i-PrOH - McOH	Hg(NO ₃) ₂ , 0.31	2 h	OMe, 45; OPr-i, 25; ONO ₂ , 30		
54		t-BuOH - McOH	Hg(NO ₃)2, 0.31	2 h	OMe, 31; OBu-t, 20; ONO2, 51		
66	Et ₂ I, 0.09	AcOH	AgOAc, 0.17	10 min	OAc, 50	OAc, 50	6,1,9
66	Me2CI, 0.15	CF3C02H	None	17 h	CI(SM), 100		
57	Me2Br, 0.14	CF3CH2H	None	17 h	Br(SM), 100		
58.	Me21, 0.10	CF3C02H	None	18 h	I(SM), 54; O ₂ CCF ₃ , 46		
20		CF3CO2H	NaO ₂ CCF ₃ , 1.0	18 h	I(SM), 59; O ₂ CCF ₃ , 41		-
60		CF3C02H - AcOH	None	6 d	I(SM); O ₂ CCF ₃ ; AOc		
61		CF3C02H	Ag02CCF ₃ , 0.17	0.5 h	$O_2 CCF_3, 100$		≈ -
62		CF3CO2H - AcOH	Ag20, 0.20	5 min	O2CCF3, 82; OAc, 28		
63	Me ₂ Cl, 0.15	CF ₃ CO ₂ H	AgO_2CCF_3 , 0.20	0.6 h	02CCF3, 100		
64	Me2H, 0,15	CF ₃ CO ₂ H	AgO_2CCF_3 , 0.20	1 h	H(SM), 50; 02CCF3, 50		
66	Et21, 0.10	CF3C02H	None	7 d	02CCF3, 44	02 CCF3, 56	-
99		CF3CO2H	Ag02CCF3, 0.17	10 min	02CCF3, 75	02 CCF3, 25	u'm')
67	Et21, 0.16	CF3C02H	Ag02 CCF3, 0.17 + Na02 CCF3, 10 10 min	10 10 min	02CCF3, 78	02 CCF3, 22	u '
68	$Et_2H, 0.10$	CF3C02H	AgO_2CCF_3 , 0.26	5 h	02CCF3,40	02 CCF3, 60	
69	EtMel, 0.10	CF3CO2H	None	4 d	02CCF3, 36	02 CCF3, 64	-
70		CF3C02H	$AgO_2 CCF_3$, 0.20	10 min	O2CCF3, 54	02 CCF3, 46	

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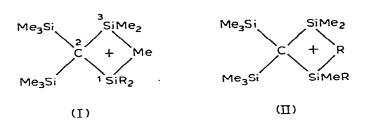
doubt on this identification. (see Experimental section.) c Heated in bath at 90°C. f Only about half of the NaNO₃ dissolved. ^B Most or all of the mercury(II) salt removed undissolved. ^B Undissolved NaCl was present throughout. ^I The reaction appeared to be complete within a few seconds of mixing. ^J Very little reaction had occurred, but small peaks for TsiSiMe₂O₂CCF₃ and TsiSiMe₂OAc were present in roughly 3/1 ratio.^E Immediate precipitation of Agl occurred on mixing. ^I Reaction was slower than with TsiSiMe₂O2CCF₃ and TsiSiMe₂OAc were present in roughly 3/1 ratio.^E Immediate precipitation of Agl occurred on mixing. ^I Reaction was slower than with TsiSiMe₂O1, ^m At room temperature.ⁿ The product mixture gave ν (CO) bands at 1766 and 1726 cm⁻¹.

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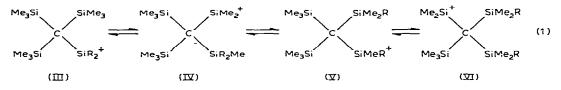
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could then attack either the ion III to give unrearranged or the ion IV to give rearranged product. We cannot rule out this possibility, but we favour the bridged intermediate I, primarily on the basis of a consideration of the propor-



tions of products. In a statistically determined equilibrium (i.e. any specific effects of the R groups being neglected), the ion IV would be nine times as likely as III, and so even in the absence of any steric favouring of attack at Si(3), 90% of rearranged and 10% of unrearranged product would be expected, whereas only 50% of rearrangement is formed with TsiSiEt₂I in AgOAc — AcOH (Rct. 55). Even more significantly, if reversible migration of Me groups occurs rapidly, giving ions III and IV, similar migrations of the R groups would be expected, to give ions of the type V and VI and these would lead to products of the type (Me₃Si)₂C(SiMeRY)(SiMe₂R) and (Me₃Si)C(SiMe₂X)(SiMe₂R)₂ which we have never observed; in fact, in a statistically-determined equilibrium the ions of the type V and VI would comprise 88% of the mixture, and such products would be expected to dominate *.

We cannot be sure that the Ph groups would migrate readily in the systems, though this would be expected in the light of their very facile migrations in carbonium ions and their high bridging ability in phenylaluminium compounds (see below) [7], and certainly no great difference would be expected between the migrating abilities of Me and Et groups.

We also favour the bridged intermediate because the system seems to have nothing to gain by going to the mixture of classical ions (though it might still do so incidentally), whereas formation of the bridged species I in an anchimerically-assisted process as X^- separates means that generation of an actual siliconium ion, which appears to be a highly disfavoured species, is avoided.

We should note that while the absence of marked increase in the proportion of SiONO₂ products on increasing the nitrate concentration in various media rules out formation of such products by concerted attack of separated nitrate ion at Si(1) or (with accompanying Me migration) at Si(3) as X^- is being abstracted, this observation does not, in itself, preclude such concerted attack involving the nucleophile and electrophile in association (either covalently

^{*} Observation of small amounts of rearranged products of this type would not preclude the intermediacy of bridged-ions, since it would not be surprising to find that the ions of type I could undergo some transformation into those of type II.

bonded, as in $Hg(NO_3)_2$, or electrostatistically linked in an ion pair, as with AgNO₃). However, not only would such processes be highly unlikely for steric and entropic reasons, but furthermore such reactions leading to entry of the nucleophile at Si(1) or Si(3) would have to be assumed to be in competition not only with one another but also with open systems involving concerted attack of the solvents as the nucleophile. This would present a highly complex picture, and many coincidences would have to be postulated to explain features of the product distributions which can be fairly interpreted in terms of a cationic intermediate.

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There can be little doubt that in the media used, ion pairs must play important roles. In the reactions with silver salts, not only will $AgNO_3$, for example, be mainly present as ion pairs, but after the formation of AgX the nitrate ion can be expected largely to remain paired with the ion I, and become incorporated into the SiONO₂ product. Thus it is easy to understand why added nitrate ion has little, if any, effect on the SiONO₂/SiOMe product ratio from TsiSiPh₂I (Rcts. 1—3) or TsiSiMe₂I (Rcts. 16—19) with AgNO₃ — MeOH. However, there might also be some separation of the initial ion pairs, and thus for TsiSiMe₂I with AgNO₃ — AcOH added nitrate does increase the SiONO₂/SiOAc ratio (Rcts. 24, 25), but the increases are markedly less than the increases in the concentration of metal nitrate. The situation is more complex with mercury(II) salts, HgY₂, since either Y⁻ or HgY₂X⁻ might form the counter anion, but, in fact, the effects of added nitrate ion on Hg(NO₃)₂ reactions in MeOH and AcOH are similar to those observed with AgNO₃ (Rcts. 28, 29; 30, 31).

Some additional features of interest in the results are as follows:

(1) The mercury(II) halides $HgCl_2$ and $HgBr_2$ are much less reactive than $Hg(NO_3)$, $Hg(OAc)_2$, and $HgSO_4$ (Rcts. 28, 31, 37, 38, 40, 41), which is in keeping with the generally lower electrophilic reactivity of the halides [8]. Not surprisingly, since Hg—Cl bonds must be formed, addition of an excess of NaCl to $Hg(OAc)_2$ — AcOH considerably reduces the rate, and leads to a SiOAc/SiCl product ratio similar to that from $HgCl_2$ — AcOH (Rcts. 45, 47). No silicon sulphate is obtained from $HgSO_4$ in MeOH or AcOH (Rcts. 39, 44), and $HgSO_4$ — MeOH is the only reagent system used which converts TsiSiMe₂I exclusively into TsiSiMe₂OMe.

(2) With $AgNO_3 - MeOH$ the SiOR/SiONO₂ product ratio from TsiSiMe₂I is ca. 3/1 (Rct. 16), while with $AgNO_3 - i$ -PrOH it is ca. 1/2 (Rct. 20), indicating (the different solvent molarities and solvation effects being neglected) that MeOH is ca. 6 times as effective a nucleophile towards the cationic intermediate as i-PrOH, but it is a little surprising that no significant amount of TsiSiMe₂-OPr-i is formed with $AgNO_3$ in 1/1 i-PrOH - MeOH (Rct. 26). There is qualitative but not quantitative correspondence between the results for separate and mixed solvents; thus, for TsiSiMe₂I with $AgNO_3$ in MeOH, the SiOMe/SiONO₂ product ratio is ca. 3/1 (Rct. 16), while with $AgNO_3$ in AcOH the SiOAc/ SiONO₂ ratio is ca. 10/1, and so on the simplest reasoning a SiOAc/SiOMe ratio of ca. 3/1 would be expected with $AgNO_3$ in 1/1 MeOH - AcOH, whereas the actual ratio is 1.6/1 (Rct. 27). With $Hg(NO_3)_2$ in 1/1 MeOH - i-PrOH a SiOMe/ SiOPr-i ratio of ca. 1.7/1 would be expected from the results in the separate solvents (Rcts. 29, 30), while the actual ratio is 1.6/1 (Rct. 34). The high SiOAc/SiOMe ratio (ca. 3/1) obtained with $Hg(OAc)_2$ in 1/1 MeOH - AcOH (Rct. 36) was expected, since the OAc group can be supplied by both the solvent and the salt, but the even higher SiOAc/SiOMe ratio (ca. 4/1) and the absence of SiONO₂ product obtained with $Hg(NO_3)_2$ in 1/1 AcOH — MeOH (Rct. 36) is most puzzling. Also surprising is that the SiOAc/SiOMe product ratio from TsiSiPh₂I in 1/1 MeOH — AcOH is lower with AgOAc than with AgNO₃ (Rcts. 7, 11).

(3) The proportion of alkoxy product, SiOR, from $TsiSiMe_2I$ with AgNO₃ or $Hg(NO_3)_2$ in an alcohol ROH falls on going from MeOH to i-PrOH (Rets. 17, 20; 28, 30) as would be expected on steric grounds, and in the case of $Hg(NO_3)_2$ there is a further fall on going to t-BuOH (Ret. 33), but with AgNO₃ the proportion of SiOBu-t (Ret. 23) is the same as that of SiOPr-i product (Ret. 22). It is surprising that the effects of steric hindrance on going to the branched alcohols, especially to t-BuOH, are not larger.

The fact that a substantial amount of $TsiSiMe_2OPr$ -i is formed with $Hg(NO_3)_2$ in 1/1 i-PrOH — MeOH (Rct. 34) whereas none was detected with AgNO₃ in this medium (Rct. 26) is in keeping with the higher SiOPr-i/SiONO₂ ratio obtained with $Hg(NO_3)_2$ than with AgNO₃ in i-PrOH alone (Rcts. 20, 30). A substantial proportion of SiOBu-t product is also formed from $Hg(NO_3)_2$ in 1/1 t-BuOH — MeOH (Rct. 35).

(4) Roughly the same SiOR/SiOMe ratios (R = Ac, i-Pr, or t-Bu) are obtained from TsiSiMe₂I and TsiSiMe₂H with both Hg(NO₃)₂ and Hg(OAc)₂ in ROH — MeOH mixtures (Rcts. 34, 53; 36, 51; 35, 54; 38,52), as expected for formation of a common intermediate. The proportion of SiONO₂ product from Hg-(NO₃)₂ is probably higher for TsiSiMe₂H (Rct. 53) than for TsiSiMe₂I in i-PrOH — MeOH (Rct. 34), and certainly so in t-BuOH — MeOH (Rcts. 35, 54). This does not represent an anomaly, however, since different counter anions, with different abilities to release nitrate ion, are produced by the initial electrophilic attack, viz. HgI(NO₃)₂⁻ and (notionally) HgH(NO₃)₂⁻. (The latter ion is most unlikely to exist for a significant length of time.)

(5) If the cationic intermediates I became fully separated before reaction with the nucleophiles, we should expect the product distributions from TsiSi- Ph_2I to be similar to those from TsiSiMe₂I under given conditions, since the silicon centre under attack would be very similar in the two cases. In fact the distributions differ, although the differences are not large if the experimental uncertainty in the values is kept in mind. However, with TsiSiPh₂I the products result from attack at only Si(3), while with TsiSiMe₂I they come from attack at both Si(1) and Si(3), and since these two centres may not become identical before the nucleophile attacks (the leaving group in association with the electrophile still being in the neighborhood of Si(1)), they could give rise to different product distributions.

(6) When a mixture of 0.10 mol each of TsiSiPh₂I and TsiSiMe₂I was treated with a deficiency (0.13 mol) of AgNO₃ in MeOH, $(Me_3Si)_2C(SiPh_2Me)$ -(SiMe₂OMe) and TsiSiMe₂OMe were formed in a ratio of ca. 43/57, indicating that the dimethyl compound is the more reactive by a factor in the region of 1.6/1. If the bridged ion I is formed in the rate-determining step, as we postulate, then the factors which might be expected to favour formation of the ion TsiSiPh₂⁺ compared with TsiSiMe₂⁺ (viz. conjugation with the phenyl groups, and greater release of steric strain on ionization) would operate only to a limited extent, if at all.

(7) The nitrate $(Me_3Si)_3CSiMe_2ONO_2$ was obtained in excellent yield, free from other products, by treatment of $(Me_3Si)_3CSiMe_2I$ with AgNO₃ in the presence of LiNO₃ in glyme.

Reactions in trifluoroacetic acid

We turned to the use of trifluoroacetic acid because we reasoned that if the TsiSiR₂X species can give cationic intermediates (whether bridged or not), reaction might be expected to occur with this solvent even without added salts, since it is known to promote very strongly the $S_N 1$ reactions of alkyl halides and related species [9]. It will be seen from the results in Table 1 that TsiSiMe₂I, TsiSiEt₂I and TsiSiEtMeI do react with the acid alone, though fairly slowly even at 90° C, and that the rearrangements we associate with cationic intermediates occur (Rcts. 58, 65, 69). The rearranged trifluoroacetate accounts for roughly 55% of the products from TsiSiEt₂I and 44% from TsiSiEtMeI. The determination of product ratios by ¹H NMR spectroscopy is subject to a fairly large uncertainty in these systems (see Experimental section), and the apparent formation of slightly less rearranged than unrearranged product from TsiSiEt-MeI may not be real.

As expected, the presence of silver trifluoroacetate generally increases the rate of reaction (Rcts. 66, 70). Even the chloride TsiSiMe₂Cl reacts readily (Rcts. 56), but in competition for a deficiency of AgO_2CCF_3 between $TsiSiMe_2I$ and TsiSiMe₂Cl only the iodide reacted. With TsiSiEt₂I the proportion of rearranged product is greater with $AgO_2CCF_3 - CF_3CO_2H$ than with CF_3CO_2H alone (Rcts. 65, 66). A possible explanation of this is that the nucleophilic attack by trifluoroacetate ion or trifluoroacetic acid takes place while the Si(1)silicon centre is still shielded by the formed AgI, which may taken a significant time to diffuse away. The proportion of rearranged product obtained from Tsi- $SiEt_2I$ with $AgO_2CCF_3 - CF_3CO_2H$ is not changed by the addition of NaO₂-CCF₃ (Rcts. 66, 67). Interestingly, in the reaction of TsiSiEt₂H with AgO₂C- $CF_3 - CF_3CO_2H$ (Rct. 68), the unrearranged product predominates, and this represents the only case in which it is clearly so. It is conceivable that the forming AgH interacts with the solvent as it separates, and generates additional trifluoroacetate ion in the neighbourhood of Si(1), but we have previously noted that the presence of only one Si-H bond in trisylsilicon systems, by markedly reducing the steric crowding, permits direct displacement to occur [1], and there might be some contribution from a process involving nucleophilic attachment of trifluoroacetate at Si(1) as the Si-H bond breaks, with either an open or cyclic transition state.

It is noteworthy that the reaction of $TsiSiMe_2I$ with CF_3CO_2H alone is not accelerated by the presence of sodium trifluoroacetate (Rcts. 58, 59), suggesting that nucleophilic attack plays no significant part in the rate-determining step, as we have assumed above. Trifluoroacetic acid (while a very weak nucleophile [10]) is, of course, a quite powerful electrophile, and can be assumed to form a covalent bond to the iodine (to give HI) in the halogen abstraction.

It is in keeping with our mechanistic proposals that while $TsiSiMe_2I$ does not react with AcOH alone, both $TsiSiMe_2OAc$ and $TsiSiMe_2O_2CCF_3$ are produced, in ca. 1/3 ratio, in the very slow reaction which occurs in 1/1 AcOH – CF₃-CO₂H at 90° (Rct. 60). A similar ratio, actually 28/82, is produced in the rapid

reaction which takes place at room temperature with $1/1 \text{ AcOH} - \text{CF}_3\text{CO}_2\text{H}$ in which silver oxide has been dissolved (Rct. 62).

The nature of the methyl-bridged cation

The formation of the bridged cation I might seem highly improbable in the light of the lack of any comparable structure in the very extensive chemistry of carbonium ions, or even, as far as we are aware, of any example of 1,3-methyl migration within a carbonium ion. However, the cation I becomes plausible when the close analogy to methyl bridging in aluminium compounds is considered. Thus the relevant bridged portion of the electron-deficient silicon species I is actually iso-electronic with the corresponding section of Al_2Me_6 , and we can assume that the detail of the bonding in the bridge of I is closely similar to that in Al_2Me_6 .

Even if cation I has no real existence, the observed methyl migration would still have to be accounted for in terms of a transition state close to I in structure, and the analogy with bonding in Al_2Me_6 would still apply. Models show that in $(Me_3Si)_3CSiR_2X$ compounds, some Me groups are held in very close to the silicon atom of the SiR₂ entity, so that as X⁻ leaves very little movement of a Me group would be needed to form the bridge in cation I, and there would be relatively little entropy loss.

Concluding Remarks

Our mechanistic proposals satisfactorily account for the great majority of our observations, but several anomalies, which have been pointed out, remain. The reactions we describe are wholly unprecedented, and full definition of the details of the mechanism(s) involved will require much more extensive studies, probably including kinetic investigations. It is relevant to note that the (evidently very complex) mechanisms of solvolyses of alkyl halides catalysed by silver or mercury salts are still very imperfectly understood in spite of the large number of kinetic studies extending back some 70 years [11].

Experimental

Starting materials

The preparation of the $TsiSiR_2X$ compounds used as reactants have been described previously [2].

Preparative scale reactions

Details of some typical procedures used in reactions leading to isolated products or recovery of unchanged starting material are as follows.

(i) Reaction of $TsiSiPh_2Cl$ with $AgNO_3 - MeOH$. A solution of $TsiSiPh_2Cl$ (0.20 g, 0.44 mmol) and $AgNO_3$ (0.10 g, 0.58 mmol) in MeOH (15 cm³) was refluxed for 2 h then added to water. Extraction with hexane, followed by separation, drying (MgSO₄), and evaporation of the organic layer, left a solid which was shown by its ¹H NMR spectrum to be unchanged $TsiSiPh_2Cl$.

(ii) Reaction of $TsiSiPh_2I$ with $AgNO_3 - AcOH$. A solution of $TsiSiPh_2I$ (0.20 g, 0.44 mmol) and $AgNO_3$ (0.10 g, 0.58 mmol) in MeOH (15 cm³) was refluxed for 10 min. Hexane was added, and the solution was decanted from

TABLE 2

NMR SPECTRA OF (Me₃Si)₃CSiMe₂X AND (Me₃Si)₂C(SiMe₂X)(SiPh₂Me) COMPOUNDS

Compound	δ ^a (ccpm)q	Notes
TsiSiMe ₂ OAc	0.27 (s, 27H, SiMe ₃); 0.52 (s, 6h, SiMe ₂); 2.00 (s, 3H, COMe)	ь
TsiSiMe ₂ O ₂ CCF ₃	0.28 (s. 27H, SiMe ₃); 0.62 (s. 6H, SiMe ₂)	с
TsiSiMe2ONO2	0.30 (s, 27H, SiMe3); 0.63 (s, 6H, SiMe2)	
TsiSiMe ₂ OMe	0.23 (s, 27H, SiMe ₃); 0.27 (s, 6H, SiMe ₂); 3.33 (s, 3H, OMe)	
TsiSiMe ₂ OPr-i	0.18 (s, 27H, SiMe3); 0.22 (s, 6H, SiMe2); 1.18 (d, 6H, CMe2); 3.44	
	(m, 1H, OCH)	
TsiSiMe2OBu-t	0.22 (s, 33H, SiMe ₃ + SiMe ₂); 1.32 (s, 9H, CMe ₃)	
TsiSiPh ₂ Cl	0.32 (s, 27H, SiMe ₃); 7.2 – 8.1 (m, 10H, Ph)	đ
TsiSiPhMeOAc	0.34 (s, 27H, SiMe ₃); 0.90 (s, 3H, SiMe); 2.19 (s, 3H, COMe);	
	7.1–7.9 (m, 5H, Ph)	
(Me ₃ Si) ₂ C(SiMe ₂ OAc)	0.25 (s, 18H, SiMe ₃); 0.38 (s, 6H, SiMe ₂); 0.95 (s, 3H, SiMe);	
(SiPh ₂ Me)	2.2 (s, 3H, COMe); 7.0–8.0 (m, 10H, Ph)	
(Me ₃ Si) ₂ C(SiMe ₂ ONO ₂)	0.40 (s, 18H, SiMe ₃); 0.47 (s, 6H, SiMe ₂): 1.1 (s, 3H, SiMe);	
(SiPh ₂ Me)	7,2–8,2 (m, 10H, Ph)	
(Me ₃ Si) ₂ C(SiMe ₂ OMe)	0.02 (s, 6H, SiMe ₂); 0.20 (s, 18H, SiMe ₃); 0.96 (s, 3H, SiMe);	
(SiPh ₂ Me)	3.55 (s, 3H, OMe); 7.1-8.1 (m, 10H, Ph)	
(Me ₃ Si) ₂ C(SiMe ₂ OPr-i)	0.37 (s, 18H, SiMe3); 0.43 (s, 6H, SiMe2); 1.07 (s, 3H, SiMe);	
(SiPh ₂ Me)	1.5 (d, 6H, CMe ₂); 4.32 (m, 1H, OCH) 7.2-8.3 (m, 10H, Ph)	
(Me ₃ Si) ₂ C(SiMe ₂ OAc)	0.34 (s, 18H, SiMe3); 0.45 (s, 6H, SiMe2Ph); 0.66 (s, SiMe2OAc);	
(SiPhMe)	7.1-7.9 (m, 5H, Ph)	

^a In CCl₄, with CH₂Cl₂ as internal standard. ^b ν (CO) (Nujol), 1720 cm⁻¹. ^c ν (CO) (Nujol), 1765 cm⁻¹. ^d A slightly different δ value for the SiMe₃ singlet was given previously [2].

the silver iodide then added to water. The organic layer was washed several times with water, dried (MgSO₄), and evaporated, to leave a solid. This was recrystallized from methanol to give $(Me_3Si)_2C(SiMe_2OMe)(SiPh_2Me)$ (0.14 g, 87%), m.p. 162°C. (Found: C, 62.2; H, 9.0. Calcd. for $C_{23}H_{4\bar{a}}OSi_4$: C, 62.2; H, 9.0%). The ¹H NMR spectral data are given in Table 2.

(iii) Reaction of $TsiSiPh_2I$ with AgOAc - AcOH. A solution of $TsiSiPh_2I$ (0.20 g, 0.37 mmol) and AgOAc (0.085 g, 0.50 mmol) in AcOH (15 cm³) was refluxed for 10 min. Work-up as described under (ii) left a sticky residue, which was sublimed (150–160°C/0.2 mmHg) to give (Me₃Si)₂C(SiMe₂OAc)(SiPh₂Me) (0.16 g, 93%), m.p. 118°C; IR, ν (CO), 1720 and 1230 cm⁻¹ (Found: C, 61.1; H, 8.5. Calcd. for C₂₄H₄₀O₂Si₄: C, 61.0; H, 8.5%). The ¹H NMR spectral data are given in Table 2.

(iv) Reaction of $TsiSiPh_2I$ with $Hg(OAc)_2 - AcOH$. A mixture of $TsiSiPh_2I$ (0.50 g, 0.90 mmol), $Hg(OAc)_2$ (0.60 g, 2.7 mmol), and AcOH (20 cm³) was refluxed for 20 min. Work-up as under (ii), culminating in sublimation, gave (Me₃Si)₂C(SiMe₂OAc)(SiPh₂Me) (0.40 g, 92%), with physical properties identical with those given above.

(v) Reaction of $TsiSiPh_2I$ with $AgNO_3 - i$ -PrOH. A solution of $TsiSiPh_2I$ (1.0 g, 0.18 mmol) and $AgNO_3$ (0.40 g, 0.23 mmol) in i-PrOH (40 cm³) was refluxed for 15 min. Work-up as under (ii) gave a solid residue, which was separated by preparative TLC (SiO₂, hexane) into three components, (a) (Me₃Si)₂C-(SiMe₂ONO₂)(SiPh₂Me) (0.20 g, 23%), m.p. 158°C; IR, ν (ONO₂), 1590 and 1285 cm⁻¹ (Found: C, 55.6; H, 7.8; N, 2.9. Calcd. for C₂₂H₃₇NO₃Si₄: C, 55.5; H, 7.7; N, 2.9%). For ¹H NMR spectral data see Table 2. (b) (Me₃Si)₂C- (SiMe₂OPr-i)(SiPh₂Me) (0.40 g, 47%), m.p. 112°C. (Found: C, 63.6; H, 9.4. Calcd. for $C_{25}H_{44}OSi_4$: C, 63.5, H, 9.3%). For ¹H NMR spectral data see Table 2. (c) A solid (0.031 g, ca. 4%) m.p. 250–258°C, the ¹H NMR spectrum of which showed resonances consistent with the formula (Me₃Si)₃CSiPh₂OPr-i, viz. δ 0.30 (s, 27H, SiMe₃), 1.06 (d, 6H, CMe₂), 4.14 (sept, 1H, CH), 7–8 ppm (m, 10H, aryl H), but with two additional peaks at δ 0.44 ppm (s, 3H) and 0.33 (s, ca. 6H) which could not be assigned, and which could be due to impurities. (Found: C, 62.7; H, 9.3. Calcd. for $C_{25}H_{44}OSi$: C, 63.5; H, 9.3%).

(vi) Reaction of $TsiSiPh_2I$ with $AgNO_3 - t$ -BuOH. A solution of $TsiSiPh_2I$ (0.50 g, 0.92 mmol) and $AgNO_3$ (0.23 g, 1.3 mmol) in t-BuOH (25 cm³) was refluxed for 15 min. Work-up as under (ii) left a solid residue, which was resolved by preparative TLC (SiO₂, hexane) into two components: (a) (Me₃Si)₂-C(SiMe₂ONO₂)(SiPh₂Me) (0.18 g, 41%), with physical constants as described under (iv); (b) an additional solid (0.20 g) which was shown by GLC (1% OV₁ on 100-120 mesh Chromosorb G at 275°C) to contain at least 3 components, none of which seemed from the ¹H NMR spectrum of the mixture to be the expected (Me₃Si)₂C(SiMe₂OBu^t)(SiPh₂Me).

(vii) Reaction of $TsiSiMe_2I$ with $Hg(OAc)_2 - AcOH$. A mixture of $TsiSiMe_2I$ (42 mg, 0.10 mmol), yellow HgO (70 mg, 3.2 mmol) and AcOH (5 cm³) was refluxed for 2 h. Work-up as in (ii) left a solid (which sublimed without melting), which was shown by its ¹H NMR spectrum (Table 2) and analysis (Found: 48.2; H, 10.4. Calcd. for $C_{14}H_{36}O_2Si_4$: C, 48.2; H, 10.4%) to be (Me₃Si)₃SiMe₂-OAc.

(viii) Reaction of TsiSiMe₂I with $AgNO_3 - LiNO_3 - MeOCH_2CH_2OMe$. A mixture of TsiSiMe₂I (0.20 g), AgNO₃ (0.10 g), LiNO₃ (0.20 mg) and glyme (10 cm³) was refluxed for 1 h. Work-up as in (ii) gave a residue, which was triturated with a little MeOH and then dried, to give TsiSiMe₂ONO₂ (0.16 g, 94%), m.p. 286-288°C (Found: C, 41.2; H, 9.5. Calcd. for C₁₂H₃₃O₃NSi₄: C, 41.0; H, 9.5%). The ¹H NMR spectrum was as shown in Table 2.

(ix) Reaction of $TsiSiMe_2I$ with trifluoroacetic acid. Trifluoroacetic acid (10 cm³) was added to a mixture of $TsiSiMe_2I$ (40 mg) and Ag_2O (40 mg), and the solution was heated under reflux. Silver iodide was precipitated very rapidly, but the mixture was heated under reflux for 1 h. The usual hexane extraction and work-up (without any purification procedure) gave $TsiSiMe_2O_2CCF_3$, m.p. $280^{\circ}C$, $\nu(CO)$ 1765 cm⁻¹ (Found: C, 41.8; H, 8.1. Calcd. for $C_{14}H_{33}O_2F_3Si_4$: C, 41.75; H, 8.3%). The ¹H NMR spectral data are shown in Table 2.

(x) Reaction of $TsiSiEt_2I$ with $AgO_2CCF_3 - CF_3CO_2H$. A mixture of silver oxide (40 mg) and $TsiSiEt_2I$ (40 mg) was dissolved in CF_3CO_2H (5 ml) at room temperature with stirring. After 5 min hexane was added, and the usual workup gave a solid residue which was identified from its ¹H NMR spectrum as a mixture of $(Me_3Si)_2C(SiMe_2O_2CCF_3)(SiEt_2Me)$ and $TsiSiEt_2O_2CCF_3$ in 3/1 ratio [Found (for mixture): C, 44.6; H, 8.7. Calcd. for $C_{16}H_{37}O_2F_3Si_4$: C, 44.6; H, 8.7%].

Determination of Product Composition by ¹H NMR Spectroscopy

The results listed in Table 1 were obtained in the following way.

The $TsiSiR_2X$ compound and any salt(s), in the amounts specified in Table 1, were placed in a 25 cm³ flask fitted with a magnetic stirrer and 10 cm³ of the appropriate solvent was added. A reflux condenser was attached, the flask was placed in a bath preheated to a suitable temperature, and stirring was begun. The reactions involving TsiSiPh₂I were all carried out at the reflux temperature, while the others were conducted with heating in a bath maintained at 90°C. [This means that in some cases the reaction was at this temperature (e.g. with AcOH as solvent) while on others (e.g. in MeOH or CF₃CO₂H) it was at the boiling point.] After the specified time, the contents of the flask were cooled, hexane was added, and the solution was decanted from any precipitated salts (and filtered if necessary), combined with the hexane washings of the precipitate, and shaken several times with water. The organic layer was dried (MgSO₄), and the solvent evaporated off. The residual solid was then dissolved in the minimum amount of CCl₄ containing 5% CH₂Cl₂, and the ¹H NMR spectrum was recorded.

Suitable sets of peaks were then chosen for comparison of peak heights or integration ratios. (In a set of 10 typical analyses no significant difference was found between product ratios derived from integrations and those from peak heights.) As far as possible analogous peaks were compared; e.g., SiOMe with SiOCHMe₂, SiOCMe₃, or SiO₂CMe, and SiMe₂ONO₂ with SiMe₂OMe. In some cases comparisons of several peaks were made and the ratios averaged.

For the reaction of TsiSiEt₂I with AgOAc — AcOH, the appearance of two clearly resolved SiO₂CMe peaks (at ca. δ 2.0 ppm) of equal heights showed that the rearranged and unrearranged products had been formed in approximately equal amounts. For the reaction of TsiSiPhMeI with AgOAc — AcOH, the 25/91 intensity ratio for SiMe₂OAc protons (δ 0.66 ppm) compared with total SiMe₃ protons (δ 0.34 ppm) indicated a rearranged/unrearranged product ratio of 76/24. Thus the larger SiO₂CMe peak could be attributed to SiMe₂OAc (δ 2.14 ppm) and the smaller to SiPhMeOAc (δ 2.19 ppm), and the heights of these peaks were in the ratio 78/22.

Estimation of the relative amounts of rearranged and unrearranged trifluoroacetates from TsiSiEt₂I and TsiSiEt₂H was more complex and less accurate. The SiMe₂O₂CCF₃ peak (δ ca. 0.62 ppm) was identified and its intensity, δx , noted. The total intensity of all the SiMe signals of (Me₃Si)₂C(SiMe₂O₂CCF₃)(SiEt₂Me) was then taken to be 21*x*, the total intensity, *y*, of all SiMe signals from the product mixture was noted, and the contribution, *z*, from the unrearranged product calculated as y -21x. The proportion of rearranged product was then given by x/[x + (z/27)]. The analogous procedure was used for TsiSiEtMeI reactions. The product proportions determined in this way are subject to a rather large uncertainty, and the values for Rcts. 66-71 in Table 1 should be regarded as reliable only to within about ±10.

The $Hg(OAc)_2 - AcOH$ and $AgO_2CCF_3 - CF_3CO_2H$ were made by dissolving HgO or Ag_2O in the appropriate acid, a little water thus being introduced.

Relative reactivities of TsiSiMe₂I and TsiSiPh₂I

(a) The appropriate silicon iodide (0.10 mmol) was dissolved in MeOH (15 cm³), and methanol (5 cm³) containing $AgNO_3$ (0.12 mmol) was added at room temperature (ca. 21°C) with rapid stirring. After 2 min the mixture was added to water.

Hexane extraction, followed by washing and drying of the extract, and evap-

oration of the solvent left a residue, which was shown by ¹H NMR spectroscopy to contain the methoxide $TsiSiR_2OMe$ and $starting material TsiSiR_2I$ in 20/80 ratio for R = Me and 16/84 ratio for R = Ph. (b) To a refluxing solution of $TsiSiPh_2I$ (0.10 mmol) and $TsiSiMe_2I$ (0.10 mmol) in MeOH (10 cm³) was added finely ground AgNO₃ (0.13 mmol). After 10 min the mixture was added to water, and the usual work-up and analysis by ¹H NMR spectroscopy showed that (Me₃Si)₂C(SiPh₂Me)(SiMe₂OMe) and TsiSiMe₂OMe had been produced in a ratio of ca. 43/57.

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